

Solid State Broadband High Power RF Amplifier

2021 - BBS2E4AHM
20 – 1000 MHz / 50 Watts

The BBS2E4AHM (SKU 2021) is suitable for EMI/RFI testing, laboratory, and ultra broadband high power linear applications. This amplifier utilizes high power push-pull MOSFET devices that provide high gain, wide dynamic range, low distortions and good linearity. Exceptional performance, long-term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, built in high quality power supply, EMI/RFI filters, machined housings and all qualified components. Empower RF's ISO9001 Quality Assurance Program assures consistent performance and the highest reliability.



Shown with Option Package 05

- Solid-state linear design
- Instantaneous ultra broadband
- Standard front panel manual gain adjust
- Suitable for CW, AM, and FM (Consult factory for other modulation types)
- Suitable for most modulation types
- 50 ohm input/output impedance
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS @ 120V_{AC}, 25°C, 50Ω system

Parameter	Symbol	Min	Typ	Max	Unit
Operating Frequency	BW	20		1000	MHz
Output Power CW	P _{SAT}	50	80		Watt
Output Power @ 1dB Gain Compression	P _{1dB}	30	40		Watt
Power Gain @ 1dB Gain Compression	G _{1dB}		46		dB
Input Power for Rated P _{SAT}	P _{IN}		0		dBm
Small Signal Gain Flatness	ΔG			±2.0	dB
Gain Adjustment Range	FGA	20			dB
Input Return Loss	S ₁₁			-10	dB
Noise Figure	NF		10		dB
Third Order Intercept Point 2-Tone @ 37dBm/Tone, 100kHz Spacing	IP3		+53		dBm
Harmonics @ P _{OUT} = 30W	H		-35	-20	dBc
Spurious Signals	Spur		-70	-60	dBc
Operating Voltage (single phase)	V _{AC}	100		240	Volt
Power Consumption @ P _{OUT} = 50W CW	P _D		550	700	Watt

MECHANICAL SPECIFICATIONS

Parameter	Value	Units	Limits
Dimensions	19 x 3.5 x 18	Inch	Max
Weight	27	lb.	Max
RF Connectors Input/Output	Type-N female		
Cooling	Built-in internal forced air cooling system		

ENVIRONMENTAL CHARACTERISTICS (Design to Meet*)

Parameter	Symbol	Min	Typ	Max	Unit
Operating Temperature	T _C	0		+50	°C
Non-operating Temperature	T _{STG}	-40		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F Method 500.4)*	ALT			30,000	Feet
Vibration / Shock*	VI / SH		Airborne		
MIL-STD-810F - Method 514.5/516.5 – Proc I					

LIMITS

Input RF drive level without damage	+10 dBm	Max
Load VSWR @ P _{OUT} = 30W	∞ @ all load phase & amplitude for duration of 1 minute 3:1 @ all load phase & amplitude continuous	-
Thermal Overload	85°C shutdown	Max

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SELECTED AVAILABLE OPTIONS (Refer to www.empowerrf.com for complete options listing)

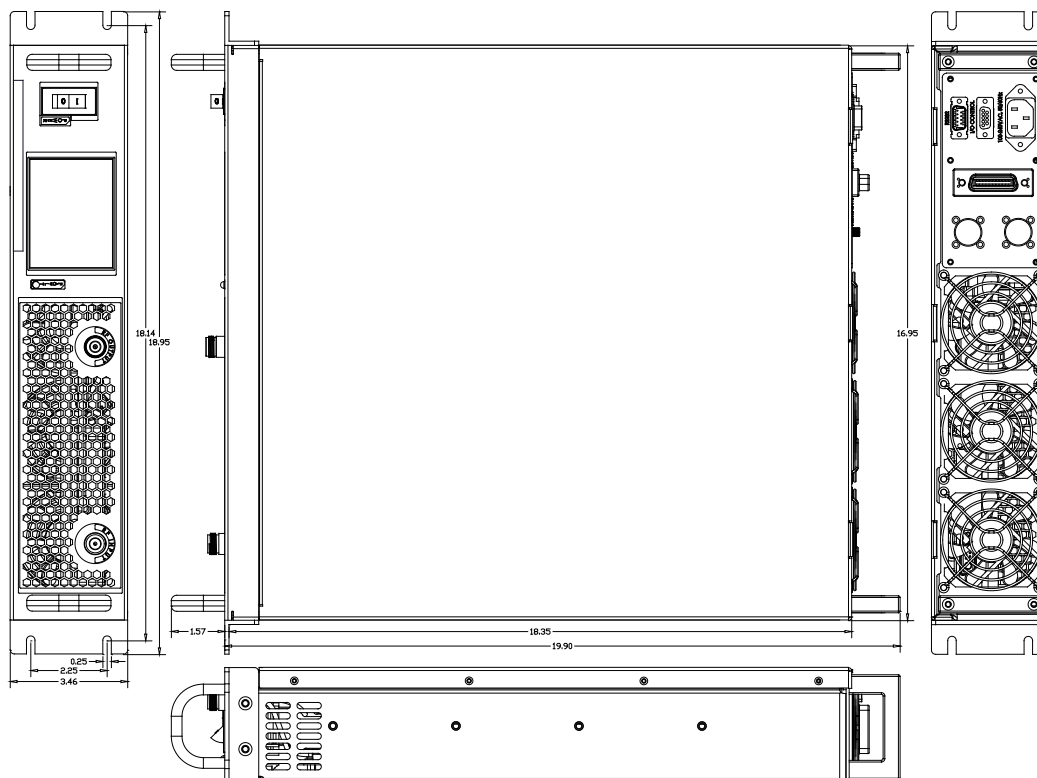
Option	Number	Description	Price
FGA	061	Front panel 10 turns manual gain adjustment.	Standard
LCD	062	Touchscreen Digital Display, including Fwd/Rev Power indication (dBm or Watt scale), Gain Adjustment, ALC Fast/Slow, On/Off, Standby mode, Fault indication, Rear panel GPIB/IEEE-488.2 and Half Duplex RS-232 or Full Duplex RS-422 remote interface. Note: Output Power is lowered by 0.5 - 0.75 dB with this option.	Call
FCN	051	Front Panel Type-N female	N/C
RCN	052	Rear Panel Type-N female	N/C

Available Option Packages: 03, 04, 05, 06

I/O INTERFACE CONNECTOR – D-Sub 9-pin, Female

Pin #	Description	Specifications	Options	
			FGA	LCD
1	Forward Test Point	Analog Voltage 0-5V _{DC} relative to Forward Power Level		√
2	Reverse Test Point	Analog Voltage 0-5V _{DC} relative to Reverse Power Level		√
3	5V Test Point	Output +5.0V _{DC} ±0.2V	√	√
4	VVA Test Point	VVA Gain Control +5.6V _{DC} ±0.2V	√	
5	EXT Shutdown	Amplifier Disable: TTL Logic High (5V) (Internally Pulled-Low)	√	√
6	12V Test Point	Output +12.0V _{DC} ± 0.5V	√	√
7	P/S Test Point	Power Supply Output voltage: +26.0-30.0V _{DC}	√	√
8	GND	Ground	√	√
9	GND	Ground	√	√

SHOWN WITH OPTION PACKAGE 05



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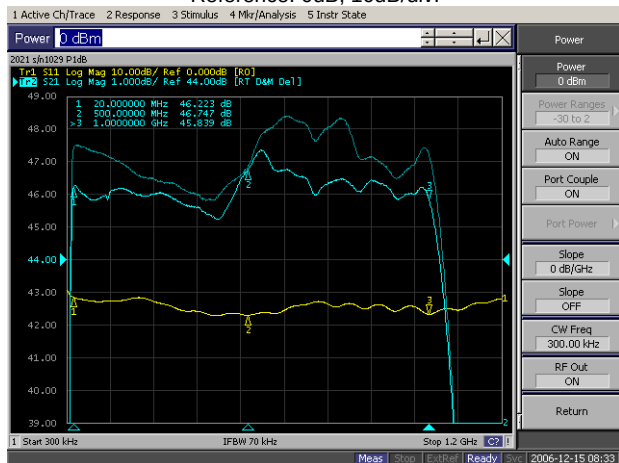
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TYPICAL PERFORMANCE PLOTS

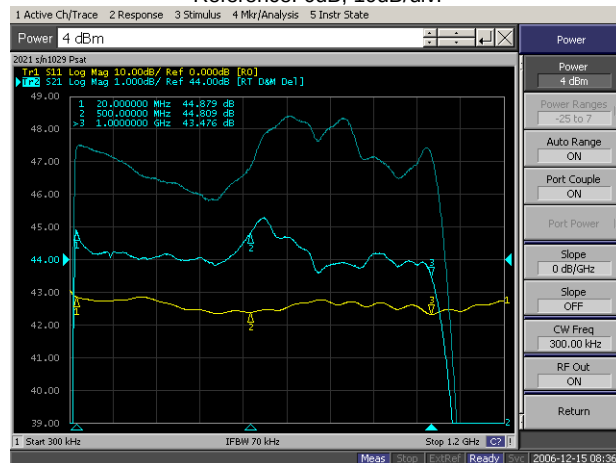
Plot 1 – Small Signal Gain and P_{1dB}

Top Curve: Small Signal Gain @ $P_{IN} = -20dBm$
 Middle Curve: Power Gain @ P_{1dB} , $P_{IN} = 0dBm$
 Reference: 44dB, 1dB/div.
 Bottom Curve: Input Return Loss
 Reference: 0dB, 10dB/div.



Plot 2 – Small Signal Gain and P_{SAT}

Top Curve: Small Signal Gain @ $P_{IN} = -20dBm$
 Middle Curve: Power Gain @ P_{SAT} , $P_{IN} = +4.0dBm$
 Reference: 44dB, 1dB/div.
 Bottom Curve: Input Return Loss
 Reference: 0dB, 10dB/div.



Plot 3 – Gain Adjustment Range

Top Curve: Maximum Gain @ $P_{IN} = -20dBm$
 Middle Curve: VVA @ Minimum Gain
 Reference: 20dB, 10dB/div.
 Bottom Curve: Input Return Loss @ Minimum Gain
 Reference: 0dB, 10dB/div.

